Adeleh Vatankhahan **Curriculum Vitae**

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| Contact | |
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|-----------------------------|---|--|--|--|--|
| Research Interests | Spintronics (Spin dynamics and transport in semiconductors) Strongly Correlated systems (Superconductivity) Modeling Nano Structures (Computational Nano Material) Condensed Matter Physics (Multiferroic Material, Topological Insulator) Quantum Monte Carlo simulations | | | | |
| Education | ☐ Ph.D. solid state physics, Shahrood University of Technology, Slands | hahrood, Iran | | | |
| | Supervisor: Dr. Tayebeh Movlarooy. | 2016-2020 | | | |
| | □ M.Sc .in Physics , Khayyam University, Mashhad , Iran | 2009 – 2011 | | | |
| | Thesis Title: transport properties of InN by Monte Carlo simula Supervisor : Dr. Hadi Arabshahi | tion | | | |
| | ☐ B.Sc . in Physics, Ferdowsi University, Mashhad, Iran | 2005 – 2009 | | | |
| ublications ournal Paper | □ Vatankhahan, A., Movlarooy, T. (2021). The effect of ed adsorption of Co and Mn atoms on spin transport properties of the Materials Science and Engineering: B, 273, 115391 □ Tarikhchi1, T, Torabi1, A, Vatankhahan, A (2021). Tuning Electrical Science and Engineering: B | borophene Nanoribbons. | | | |
| | double-walled boron nitride nanotubes using Ga atom encapsulat of Engineering Research and Applications, 11, 21-27. | ed.International. <i>Journal</i> | | | |
| | □ Vatankhahan, A, (2021). Ab Initio study of stability and elect nanotubes. <i>Journal of Engineering Research and Applicati</i> □ Vatankhahan, A., Movlarooy, T. (2020). Ab-initio study of transport of the stability of the stability and electronic production. | ons, 9, 62-65. | | | |
| | on borophene nanosheet. <i>IEEE Magnetics Letters</i> . □ Tochaei, A. A., Arabshahi, H., Benam, M. R., Vatankhahan, A. Comparison between Si/SiO 2 and InP/Al 2 O 3 based 1 <i>Experimental and Theoretical Physics</i> , 123(5), 869-874. | | | | |
| | ☐ Ghafourian, M., Nobakht, S., Arabshahi, H., Tayarani, M. H. Bazrafshan, M. (2013). Comparison of Characteristic Curve of Transport Properties in ZnO and GaAs Based MOSFETs Using Most Properties in ZnO and GaAs Based MOSFETs Using Most Properties in ZnO and GaAs Based MOSFETs Using Most Properties in ZnO and GaAs Based MOSFETs Using Most Properties in ZnO and GaAs Based MOSFETs Using Most Properties in ZnO and GaAs Based MOSFETs Using Most Properties in ZnO and GaAs Based Mosf Prop | f Drain-Source Electron | | | |
| | Arabshahi, H., Vatankhahan , A., & Tayarani, M. H. (2011). Gelectron transport properties in InN and GaN semiconductors equation using iteration model. <i>International Journal of Stechnology</i> , 1. | Comparison of low field by solving Boltzmann | | | |

| Transport in GaAs,MOSFET Transistor at The Nanoscale in High Electric Field Using Ensemble Monte Carlo Simulation ", 11 Th condensed matter physics conference of iran (2013) Vatan-khahan, H. Arabshahi," Comparison of Electron Transport Properties In Semiconductors AlN and ZnO in Iow of Field Electron and Smaller Size of Micrometers"; 11 Th condensed matter physics conference of iran (2013) | | | |
|---|---|--|--|
| Donostia Inter | (May. 2019 -Oct. 2019) | | |
| Teaching ass | istant: | (Fall 2016- present, Khayyam University) | |
| foundations of electromagnetic theory reitz Workshop software Matlab, Fortran | | (Spring 2014, Khayyam University) | |
| Computer: | Familiar with windows and Linux Operating System. Experience with C++, FORTRAN Programming, Python. Familiar with Ab-initio, DFT and NEGF simulation packages. (SIESTA, TRANSIESTA, SMEAGOL, ATK (Atomistix ToolKit)) Familiar with some computational approach like as DFT, TB, NEGF. | | |
| Language: | Software (Origin and Sigma Plot) | | |
| | Scattering Me Application. In M. Abedininity Transport in Using Ensem conference of Vatan-khahar Semiconductor 11 Th condensed Vatan-khahar By Using Iter Smaller Size (2013) Visiting Resear Donostia Inter In Prof. Aran (Geter Teaching assistical mater foundations Workshop so | Scattering Mechanisims and Electron Mobility in Application. <i>International Journal of Science and A</i> M. Abedininiya, H. Arabshahi, MH. Tayarani, A. vat Transport in GaAs, MOSFET Transistor at The Using Ensemble Monte Carlo Simulation "conference of iran (2013) Vatan-khahan, H. Arabshahi," Comparison of Semiconductors AlN and ZnO in Iow of Field Electron 11 Th condensed matter physics conference of iran (20) Vatan-khahan, H. Arabshahi, "Electron Transport By Using Iteration and Monte Carlo Simulation Smaller Size of Micrometers"; 11 Th condensed (2013) Visiting Researcher: Donostia International Physics Center In Prof. Aran Garcia-Lecce.'s Research Group. Teaching (General physics I,II) Teaching assistant: Statistical mechanics pathria foundations of electromagnetic theory reitz Workshop software Matlab, Fortran Computer: Familiar with windows and Linux O Experience with C++, FORTRAN Prof. Familiar with Ab-initio, DFT and NE (SIESTA, TRANSIESTA, SMEAGO) Familiar with some computational approximate in the prof. Software (Origin and Sigma Plot) | |